

SI2319 P-Channel 40-V(D-S) MOSEFET

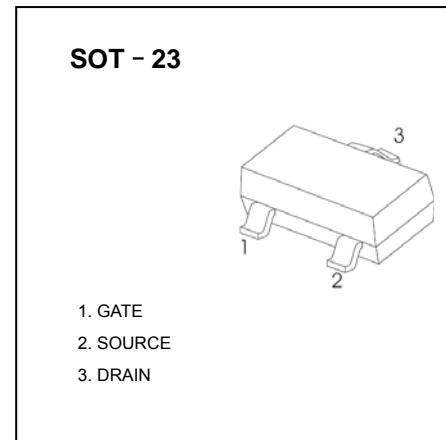
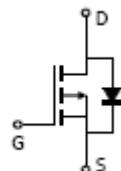
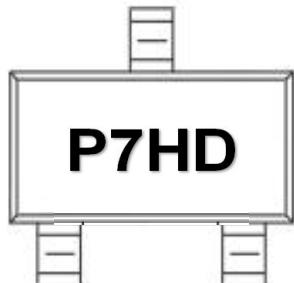
V(BR)DSS	RDS(on)MAX	ID
- 40 V	45mΩ @ - 10V 65mΩ @ - 4.5V	- 4.4A

FEATURE

- TrenchFET Power MOSFET
- Low RDS(ON)
- Surface Mount Package

APPLICATION

- ※ Load Switch for Portable Devices
- ※ DC/DC Converter
- ※ Battery Switch

MARKING**Equivalent Circuit****Maximum ratings (Ta=25°C unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	VDS	-40	V
Gate-Source Voltage	VGS	±20	
Continuous Drain Current	ID	-4.4	A
Pulsed Diode Current	IDM	-12	
Continuous Source-Drain Current(Diode Conduction)	IS	-1.25	
Power Dissipation	PD	1.25	W
Thermal Resistance from Junction to Ambient (t≤5s)	R _{θJA}	166	°C/W
Operating Junction	TJ	150	°C
Storage Temperature	T _{STG}	-55~+150	°C

SOT-23 Plastic-Encapsulate MOSFETS

MOSFET ELECTRICAL CHARACTERISTICS

Static Electrical Characteristics (Ta = 25 °C Unless Otherwise Noted)

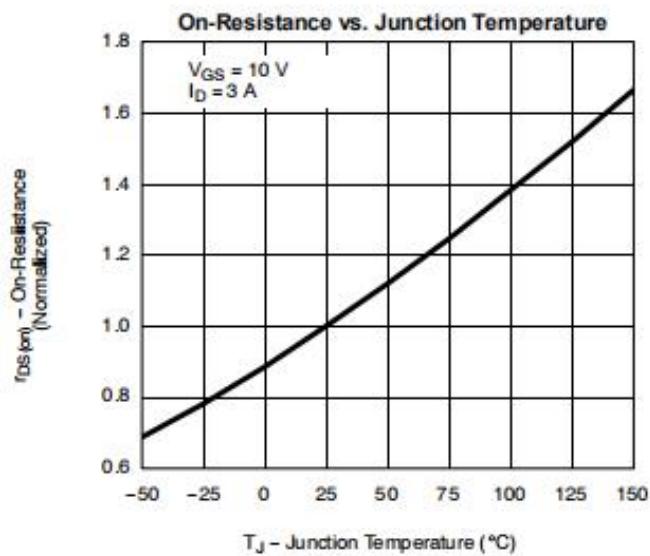
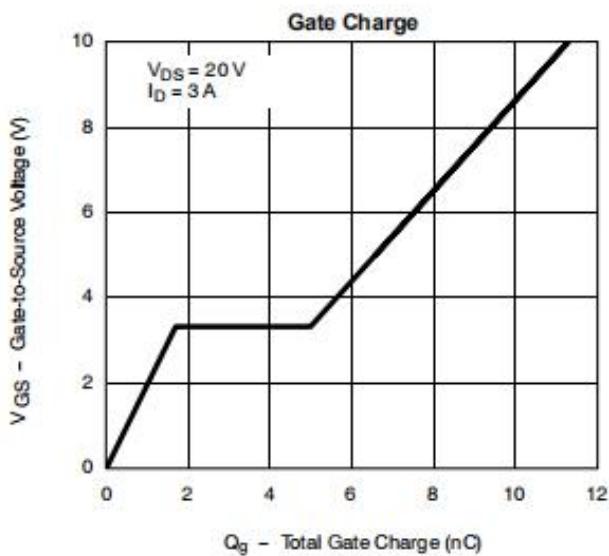
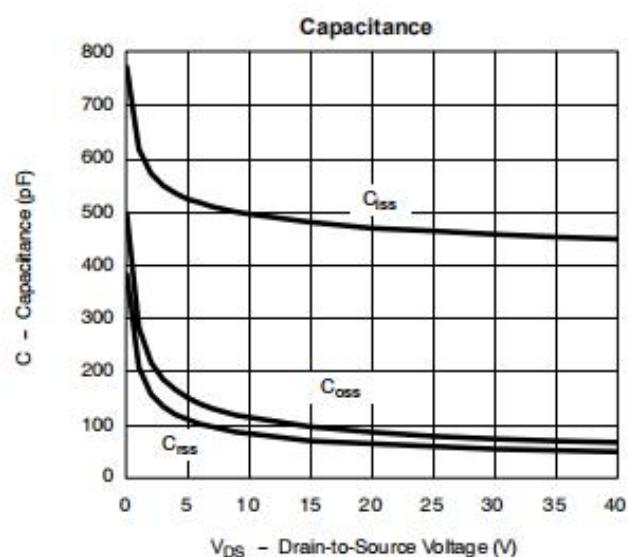
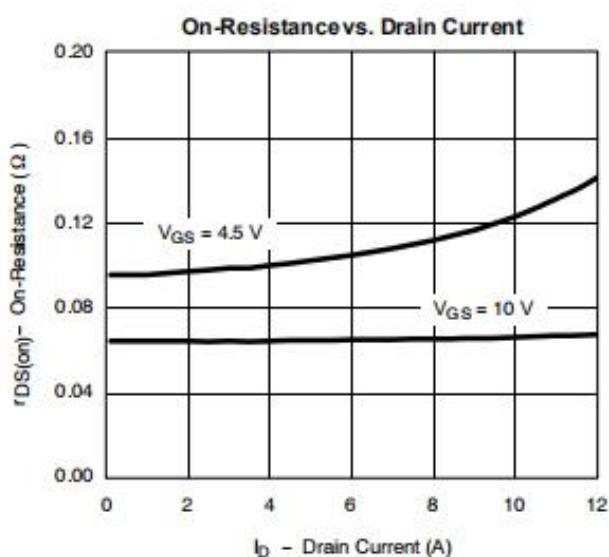
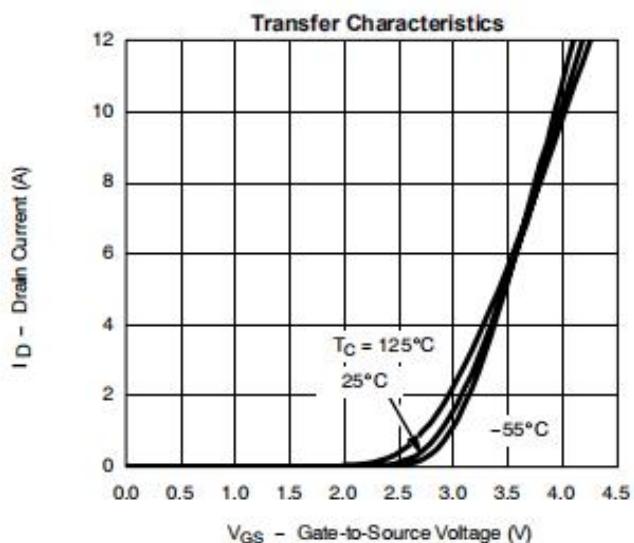
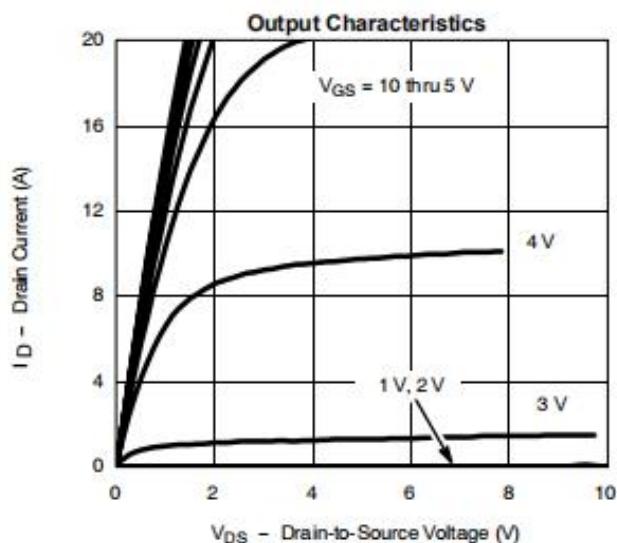
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Drain-source breakdown voltage	V(BR)DSS	VGS = 0V, ID = -250µA	-40			V
Gate-source threshold voltage	VGS(th)	VDS = VGS, ID = -250µA	-1		-3	V
Gate-source leakage	IGSS	VDS = 0V, VGS = ±20V			±100	nA
Zero gate voltage drain current	IDSS	VDS = -40V, VGS = 0V			-1	µA
Drain-source on-state resistancea	RDS(on)	VGS = -10V, ID = -3A		40	45	mΩ
		VGS = -4.5V, ID = -2.5A		56	65	mΩ
Forward transconductancea	gfs	VDS = -5V, ID = -3A		7		S
Diode forward voltage	VSD	IS= -1.25A, VGS=0V		-0.8	-1.25	V
Dynamic						
Input capacitance	Ciss	VDS = -20V, VGS = 0V, f=1MHz		470		pF
Output capacitance	Coss			85		pF
Reverse transfer capacitanceb	Crss			65		pF
Total gate charge	Qg	VDS = -20V, VGS = -10V, ID = -3A		11.5	17	nC
Gate-source charge	Qgs			1.8		nC
Gate-drain charge	Qgd			3.3		nC
Gate resistance	Rg	f=1MHz		9		Ω
Switchingb						
Turn-on delay time	td(on)	VDS=-20V RL=20Ω, ID = -1A, VGEN=-4.5 V,Rg=6Ω		7	15	ns
Rise time	tr			15	25	ns
Turn-off delay time	td(off)			25	40	ns
Fall time	tf			25	42	ns
Drain-source body diode characteristics						
Continuous Source-Drain Diode Current	IS	Tc=25°C			-1.25	A
Pulsed Diode forward Current	ISM				-20	A

Note :

1. Repetitive Rating : Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t < 5 sec.
3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production testing.

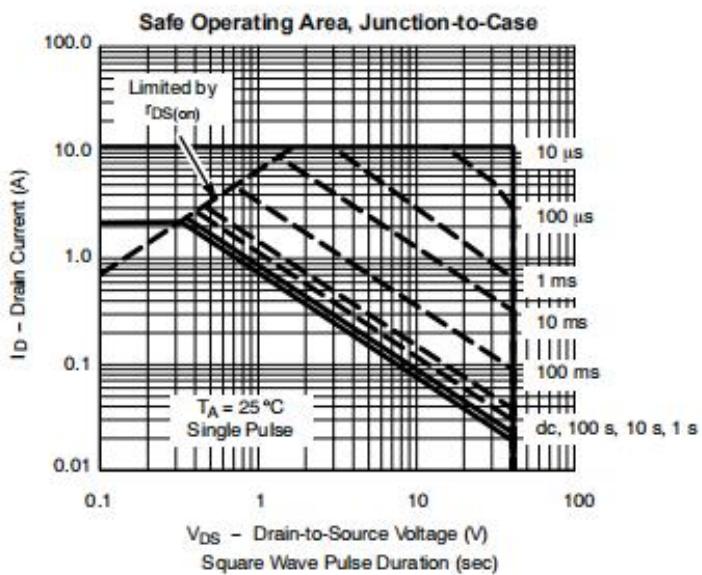
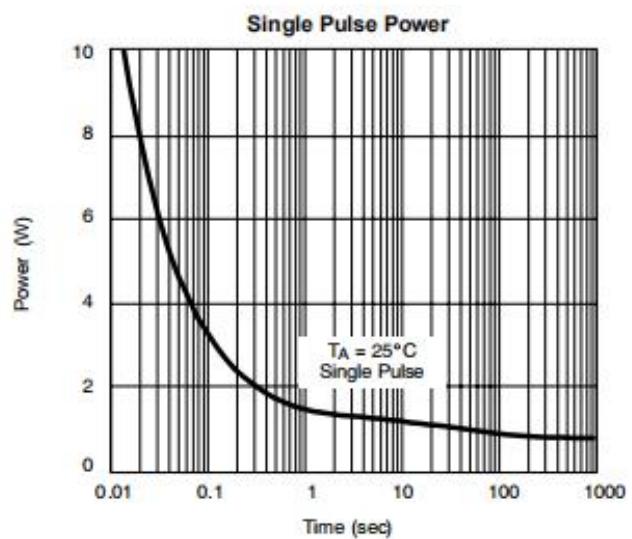
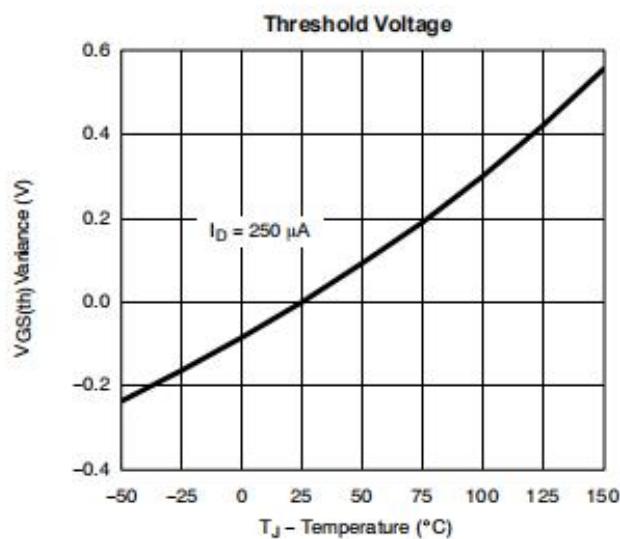
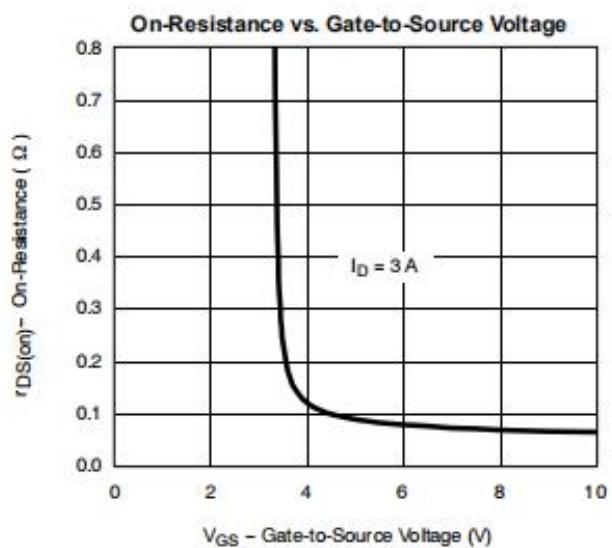
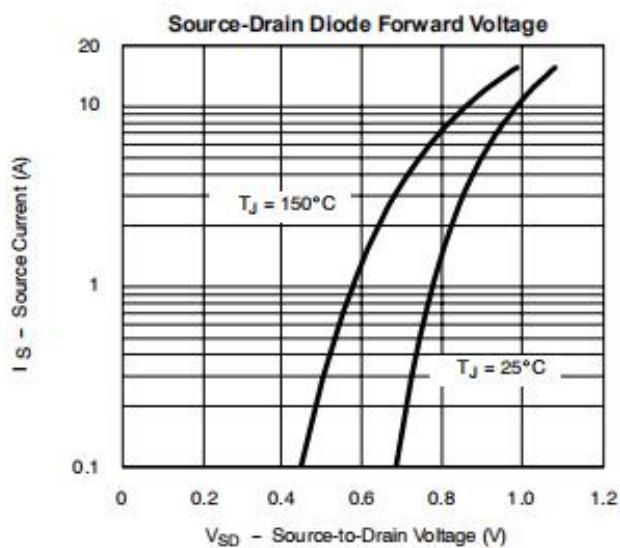
SOT-23 Plastic-Encapsulate MOSFETS

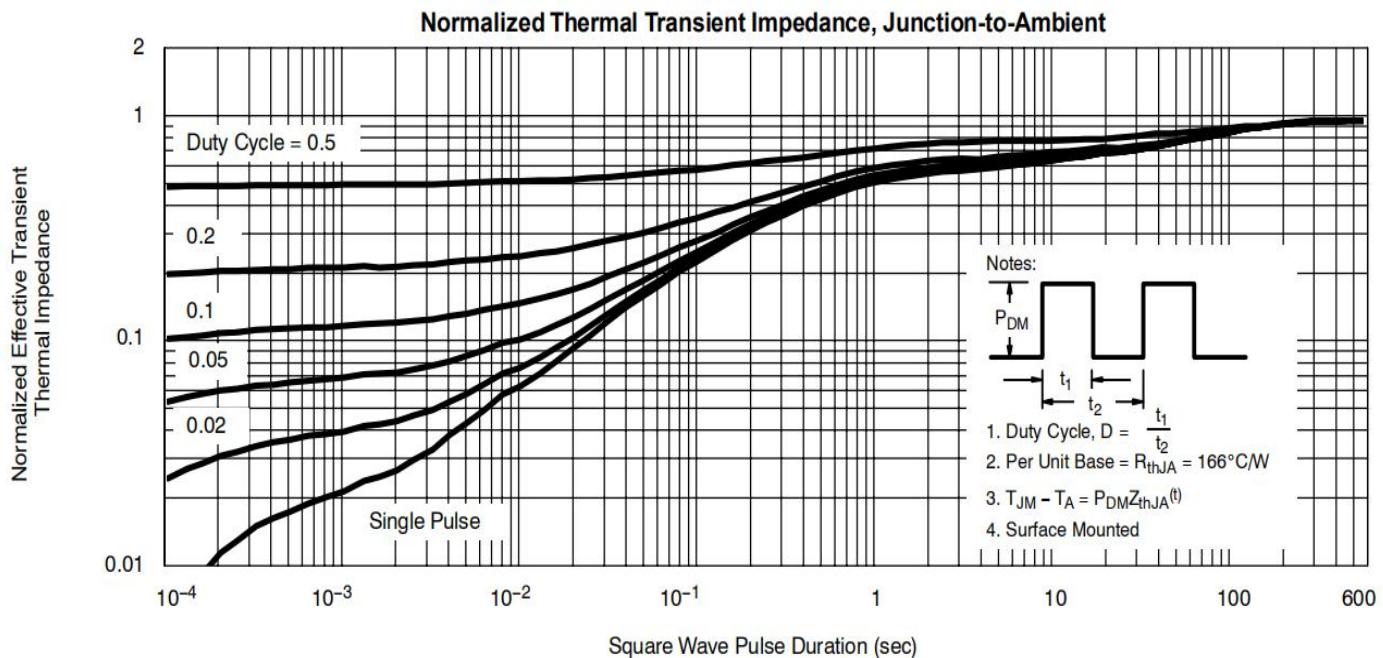
TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

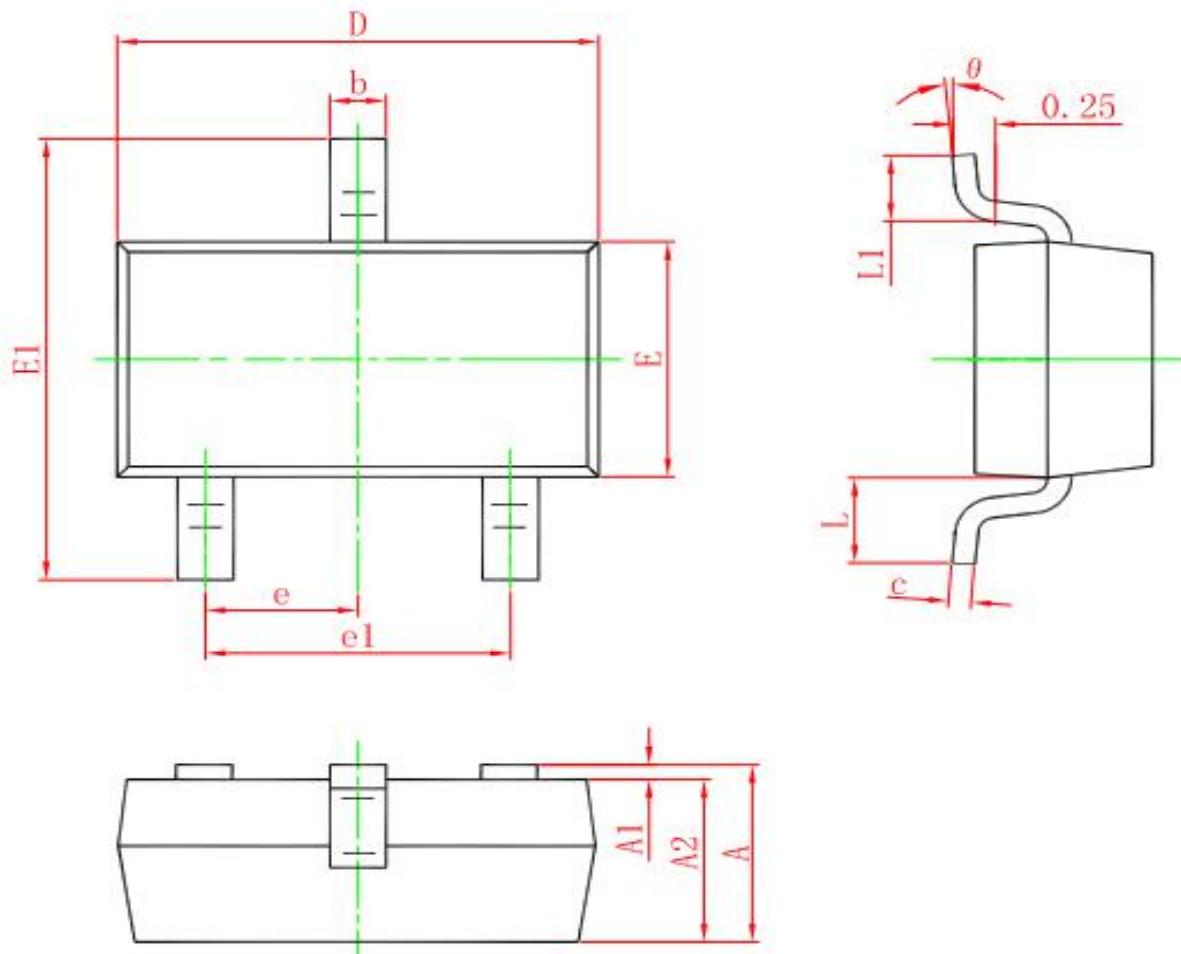


SOT-23 Plastic-Encapsulate MOSFETS

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

SOT-23 PACKAGE OUTLINE DIMENSIONS

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Youtai manufacturer:

Other Similar products are found below :

[614233C](#) [648584F](#) [MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [FW216A-TL-2W](#) [FW231A-TL-E](#) [APT5010JVR](#) [NTNS3A92PZT5G](#)
[IRF100S201](#) [JANTX2N5237](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [FCA20N60_F109](#) [FDZ595PZ](#) [STD6600NT4G](#) [FSS804-TL-E](#) [2SJ277-DL-E](#)
[2SK1691-DL-E](#) [2SK2545\(Q,T\)](#) [D2294UK](#) [405094E](#) [423220D](#) [MCH6646-TL-E](#) [TPCC8103,L1Q\(CM](#) [367-8430-0972-503](#) [VN1206L](#)
[424134F](#) [026935X](#) [051075F](#) [SBVS138LT1G](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [751625C](#) [873612G](#) [IRF7380TRHR](#)
[IPS70R2K0CEAKMA1](#) [RJK60S3DPP-E0#T2](#) [RJK60S5DPK-M0#T0](#) [APT5010JVFR](#) [APT12031JFLL](#) [APT12040JVR](#) [DMN3404LQ-7](#)
[NTE6400](#) [JANTX2N6796U](#) [JANTX2N6784U](#) [JANTXV2N5416U4](#) [SQM110N05-06L-GE3](#) [SIHF35N60E-GE3](#)